VS-HFA08PB120-N3

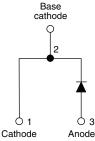
Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	8 A			
V _R	1200 V			
V _F at I _F	2.4 V			
t _{rr} typ.	28 ns			
T _J max.	150 °C			
Package	TO-247AC 2L			
Circuit configuration	Single			

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA08PB120... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 8 A continuous current, the VS-HFA08PB120... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{BBM}) and does not exhibit any tendency to "snap-off" during the t_{b} portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA08PB120... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward current	١ _F	T _C = 100 °C	8		
Single pulse forward current	I _{FSM}	t _p = 10 ms	130	А	
Maximum repetitive forward current	I _{FRM}		32		
Maximum namer dissinction	P _D	T _C = 25 °C	73.5	W	
Maximum power dissipation		T _C = 100 °C	29	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C	

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ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		1200	-	-	
		I _F = 8.0 A		-	2.6	3.3	V
Maximum forward voltage	V _{FM}	I _F = 16 A	See fig. 1	-	3.4	4.3	-
		I _F = 8.0 A, T _J = 125 °C		-	2.4	3.1	
Maximum reverse		$V_{R} = V_{R}$ rated	Occ for O	-	0.31	10	
leakage current	I _{RM}	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	See fig. 2	-	135	1000	μA
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	11	20	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -		nH			

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	I _F = 1.0 A, dI _F /dt = 200 A/µs, V _R = 30 V		-	28	-	
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C	I _F = 8.0 A dI _F /dt = 200 A/μs V _R = 200 V	-	63	95	ns
	t _{rr2}	T _J = 125 °C		-	106	160	
Peak recovery current See fig. 6	I _{RRM1}	T _J = 25 °C		-	4.5	8.0	A nC
	I _{RRM2}	T _J = 125 °C		-	6.2	11	
Reverse recovery charge See fig. 7	Q _{rr1}	T _J = 25 °C		-	140	380	
	Q _{rr2}	T _J = 125 °C		-	335	880	
Peak rate of recovery current during t _b See fig. 8	dl _{(rec)M} /dt1	T _J = 25 °C		-	133	-	
	dl _{(rec)M} /dt2	T _J = 125 °C		-	85	-	A∕µs

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	OL TEST CONDITIONS		TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	1.7	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-	
Weight			-	6.0	-	g
			-	0.21	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC 2L	HFA08PB120			

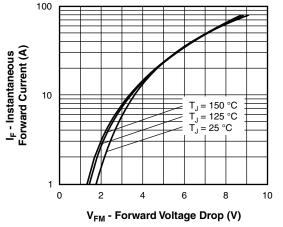
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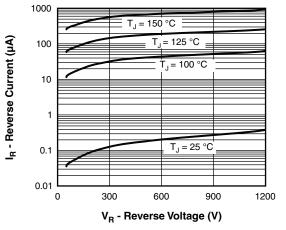
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Fig. 1 - Maximum Forward Voltage Drop Characteristics





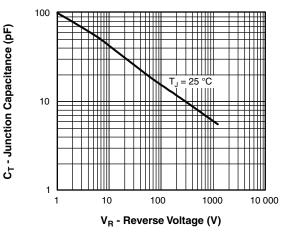
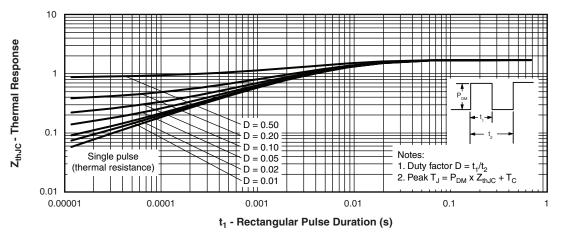


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





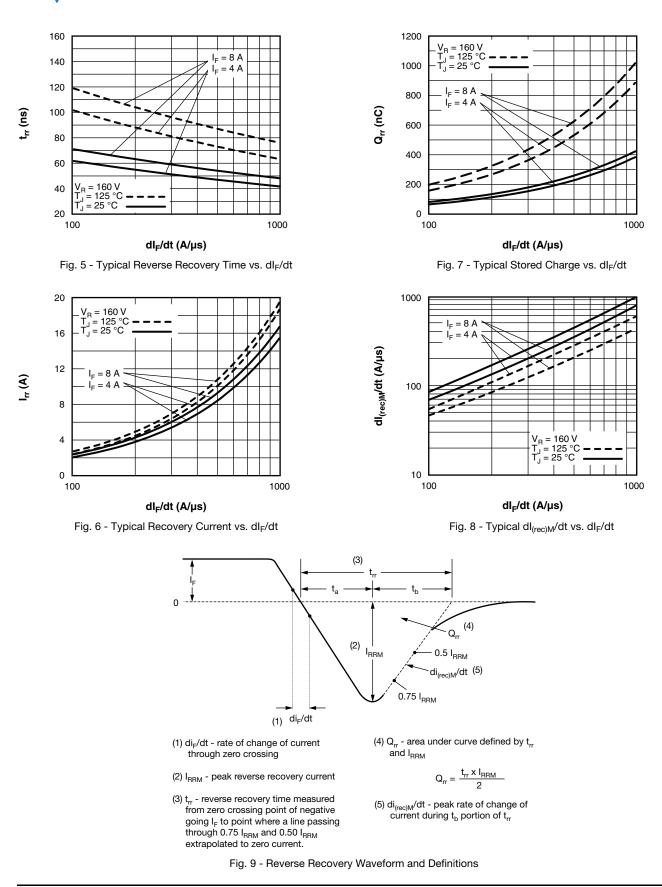
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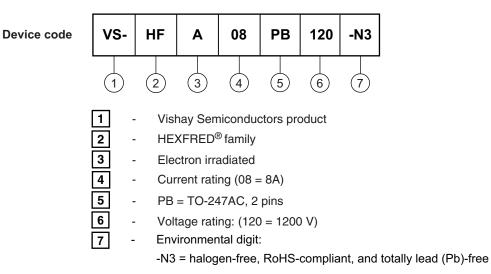
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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-HFA08Pb120-N3	25	500	Antistatic plastic tube	

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96144				
Part marking information	www.vishay.com/doc?95648			

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